Diode Semiconductor Device - Page 1 of 1



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Inclosure Materia	ai.
Glass	
Overall Length:	
	ches and 0.350 inches
Terminal Length	
1.000 inches	
Overall Diameter	
	ches and 0.265 inches
	ally-electrically Connected To Case:
Cathode	
Mounting Metho	d:
Terminal	
Features Provide	ed:
Hermetically seale	ed case
Semiconductor I	Material:
Silicon	
Voltage Rating Ir	n Volts Per Characteristic:
14.3 regulator vo	oltage
Current Rating P	Per Characteristic:
63.00 milliampere	s source cutoff current horsepower metric
Power Rating Pe	r Characteristic:
1.0 watts small-sig	gnal input power, common-collector preset
Maximum Opera	ting Tempurature Per Measurement Point:
175.0 degrees cel	lsius ambient air
Test Data Docum	nent:
81349-mil-s-1950	0 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes	commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and	d performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type A	nd Quantity:
2 uninsulated wire	e lead
Specification Da	ta:
81349-mil-s-1950	0/115 government specification
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	